

M63815P/FP/KP

8-UNIT 300mA TRANSISTOR ARRAY WITH CLAMP DIODE

DESCRIPTION

M63815P/FP/KP are eight-circuit Single transistor arrays with clamping diodes. The circuits are made of NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

FEATURES

- Three package configurations (P, FP, and KP)
- Medium breakdown voltage ($BV_{CEO} \geq 35V$)
- Synchronizing current ($I_{C(max)} = 300mA$)
- With clamping diodes
- With zener diodes
- Low output saturation voltage
- Wide operating temperature range ($T_a = -40$ to $+85^\circ C$)

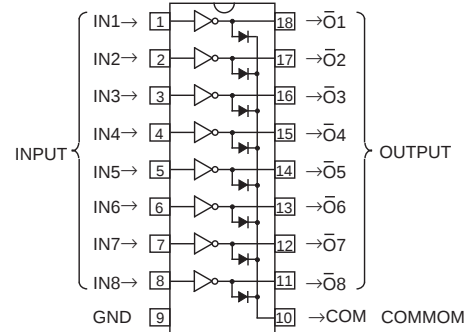
APPLICATION

Driving of digit drives of indication elements (LEDs and lamps) with small signals

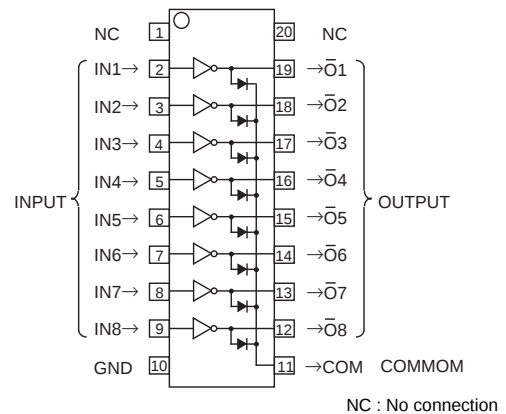
FUNCTION

The M63815P/FP/KP each have eight circuits consisting of NPN transistor. A spike-killer clamping diode is provided between each output pin (collector) and COM pin. The transistor emitters are all connected to the GND pin. The transistors allow synchronous flow of 300mA collector current. A maximum of 35V voltage can be applied between the collector and emitter.

PIN CONFIGURATION

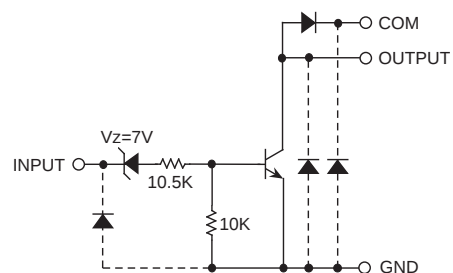


Package type 18P4G(P)



20P2N-A(FP)
 Package type 20P2E-A(KP)

CIRCUIT DIAGRAM



The eight circuits share the COM and GND.

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit: Ω

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ABSOLUTE MAXIMUM RATINGS (Unless otherwise noted, Ta = -40 ~ +85°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CEO}	Collector-emitter voltage	Output, H	-0.5 ~ +35	V
I _C	Collector current	Current per circuit output, L	300	mA
V _I	Input voltage		-0.5 ~ +35	V
I _F	Clamping diode forward current		300	mA
V _R	Clamping diode reverse voltage		35	V
P _d	Power dissipation	Ta = 25°C, when mounted on board	M63815P 1.79 M63815FP 1.10 M63815KP 0.68	W
T _{opr}	Operating temperature		-40 ~ +85	°C
T _{stg}	Storage temperature		-55 ~ +125	°C

RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, Ta = -40 ~ +85°C)

Symbol	Parameter		Test conditions	Limits			Unit
				min	typ	max	
Vo	Output voltage			0	—	35	V
Ic	Collector current (Current per 1 circuit when 8 circuits are coming on simultaneously)	M63815P	Duty Cycle no more than 50%	0	—	250	mA
			Duty Cycle no more than 100%	0	—	170	
		M63815FP	Duty Cycle no more than 30%	0	—	250	
			Duty Cycle no more than 100%	0	—	130	
		M63815KP	Duty Cycle no more than 12%	0	—	250	
			Duty Cycle no more than 100%	0	—	100	
VIN	Input voltage			0	—	30	V

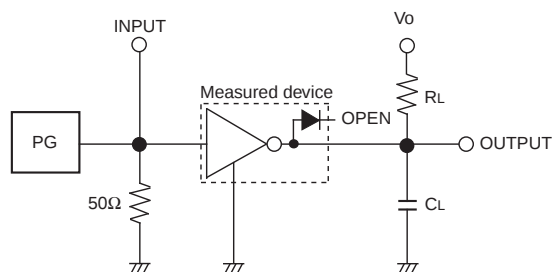
ELECTRICAL CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
V (BR) CEO	Collector-emitter breakdown voltage	I _{CEO} = 10μA	35	—	—	V
V _{CE(sat)}	Collector-emitter saturation voltage	I _{IN} = 1mA, I _C = 10mA	—	—	0.2	V
		I _{IN} = 2mA, I _C = 150mA	—	—	0.8	
V _{IN(on)}	"On" input voltage	I _{IN} = 1mA, I _C = 10mA	13	19	23	V
V _F	Clamping diode forward voltage	I _F = 250mA	—	1.2	2.0	V
I _R	Clamping diode reverse current	V _R = 35V	—	—	10	μA
h _{FE}	DC amplification factor	V _{CE} = 10V, I _C = 10mA	50	—	—	—

SWITCHING CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

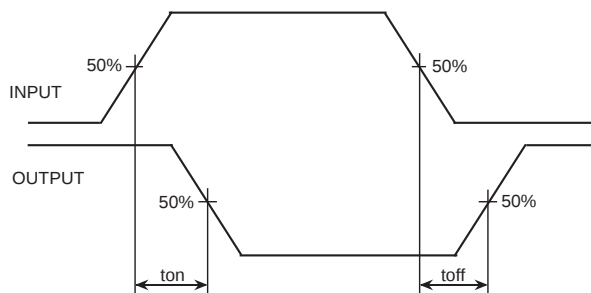
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
t _{on}	Turn-on time	C _L = 15pF (note 1)	—	140	—	ns
t _{off}	Turn-off time		—	240	—	ns

NOTE 1 TEST CIRCUIT

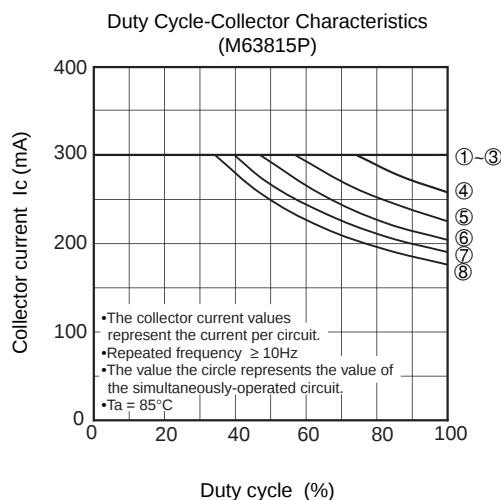
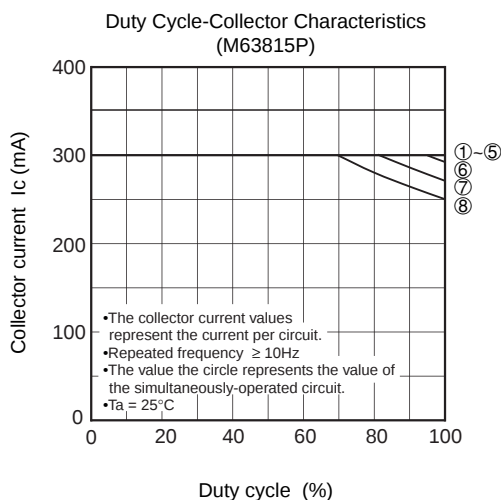
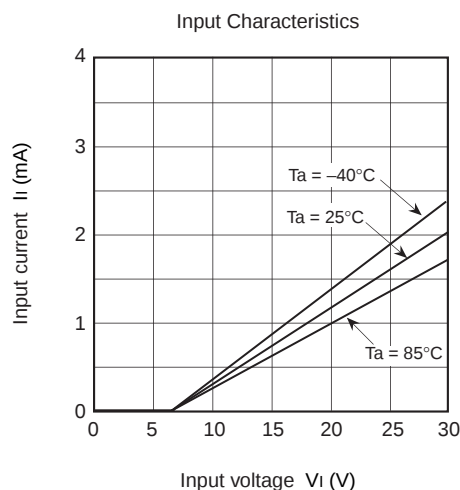
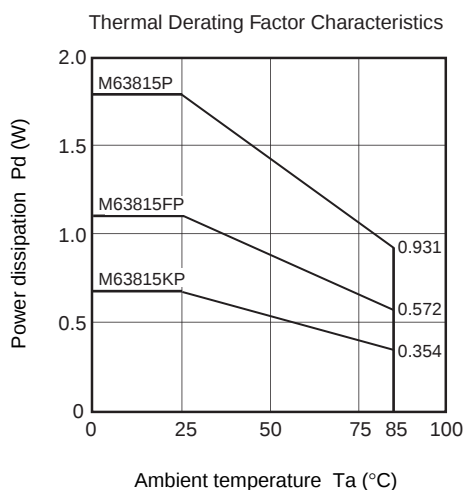


- (1) Pulse generator (PG) characteristics : PRR = 1kHz,
 $t_w = 10\mu s$, $t_r = 6ns$, $t_f = 6ns$, $Z_o = 50\Omega$, $V_{IH} = 18V$
- (2) Input-output conditions : $R_L = 220\Omega$, $V_o = 35V$
- (3) Electrostatic capacity C_L includes floating capacitance at connections and input capacitance at probes

TIMING DIAGRAM

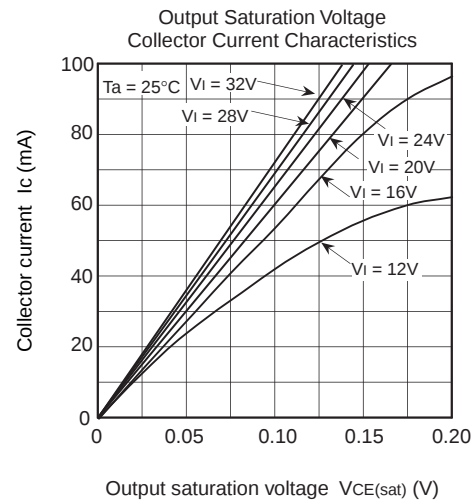
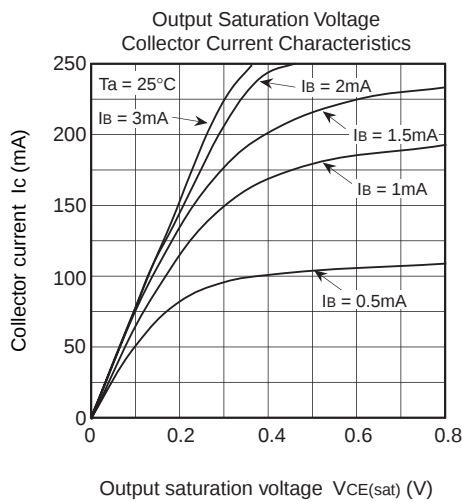
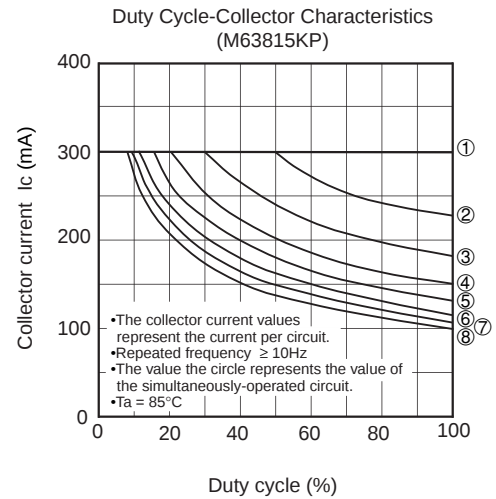
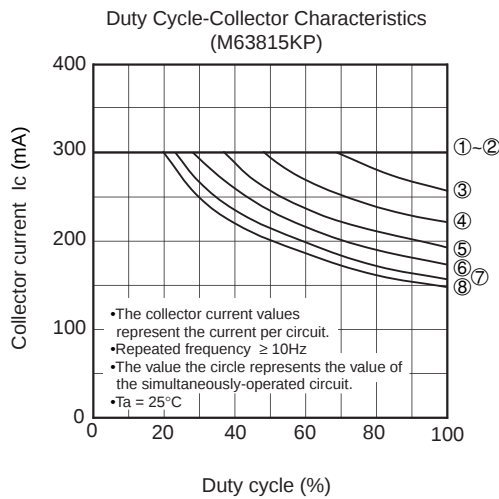
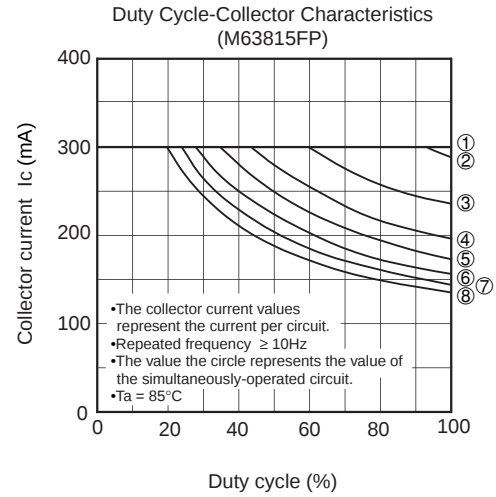
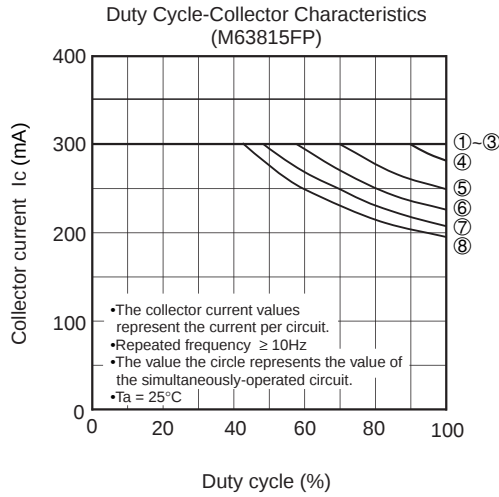


TYPICAL CHARACTERISTICS



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PRELIMINARY
Notice: This is not a final specification.
Some parametric limits are subject to change.

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